NSN 5961-01-158-4449

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View Online at https://aerobasegroup.com/nsn/5961-01-158-4449 **Inclosure Material:** Plastic **Overall Length:** 0.650 inches **Overall Height:** 0.190 inches **Overall Width:** 0.420 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -60.0 collector to base voltage, dc and -60.0 collector to emitter voltage/static/base open and -5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 10.00 amperes source cutoff current and 250.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 26.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release6713 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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